

MPS8050



NPN General Purpose Amplifier

This device is designed for general purpose audio amplifier applications at collector currents to 500 mA. Sourced from Process 30.

Absolute Maximum Ratings* TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units	
V _{CEO}	Collector-Emitter Voltage	25	V	
V _{CBO}	Collector-Base Voltage	40	V	
V _{EBO}	Emitter-Base Voltage	6.0	V	
Ic	Collector Current - Continuous	1.0	A	
T _J , T _{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C	

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:

1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units	
		MPS8050		
P _D	Total Device Dissipation	625	mW	
	Derate above 25°C	5.0	mW/°C	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction to Case	83.3	°C/W	
$R_{ ext{ hetaJA}}$	Thermal Resistance, Junction to Ambient	200	°C/W	

MPS8050

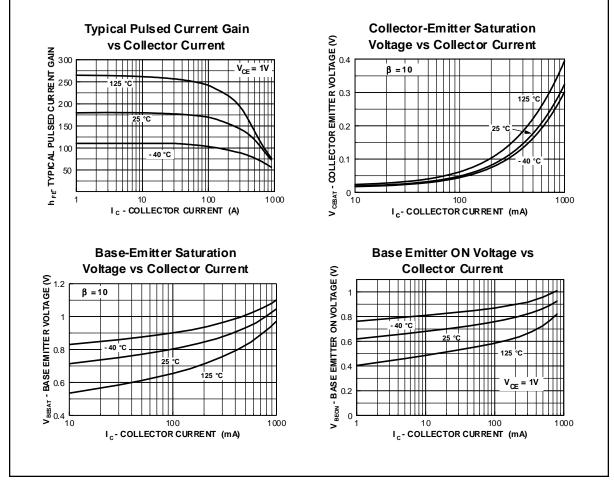
MPS8050

NPN General Purpose Amplifier (continued)

Electri	Electrical Characteristics TA = 25°C unless otherwise noted						
Symbol	Parameter	Test Conditions	Min	Max	Units		
OFF CHAF	RACTERISTICS						
V _{(BR)CEO}	Collector-Emitter Sustaining Voltage*	$I_{\rm C} = 30$ mA, $I_{\rm B} = 0$	25		V		
V _{(BR)CBO}	Collector-Base Breakdown Voltage	$I_{\rm C} = 100 \ \mu {\rm A}, \ I_{\rm E} = 0$	40		V		
V _{(BR)EBO}	Emitter-Base Breakdown Voltage	$I_{E} = 100 \ \mu A, I_{C} = 0$	6.0		V		
I _{CBO}	Collector-Cutoff Current	$V_{CB} = 35 \text{ V}, \text{ I}_{E} = 0$		0.1	μΑ		
I _{CES}	Collector-Cutoff Current	$V_{CE} = 20 \text{ V}, \text{ I}_{E} = 0$		75	nA		
ON CHAR	ACTERISTICS						
h _{FE}	DC Current Gain	$I_{\rm C} = 5.0 \text{ mA}, V_{\rm CE} = 1.0$	45	000			
		$I_{C} = 100 \text{ mA}, V_{CE} = 1.0$ $I_{C} = 800 \text{ mA}, V_{CE} = 1.0$	80 40	300			
V _{CE(sat)}	Collector-Emitter Saturation Voltage	$I_{\rm C} = 800 \text{ mA}, I_{\rm B} = 80 \text{ mA}$		0.5	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	$I_{\rm C} = 800 \text{ mA}, I_{\rm B} = 80 \text{ mA}$		1.2	V		

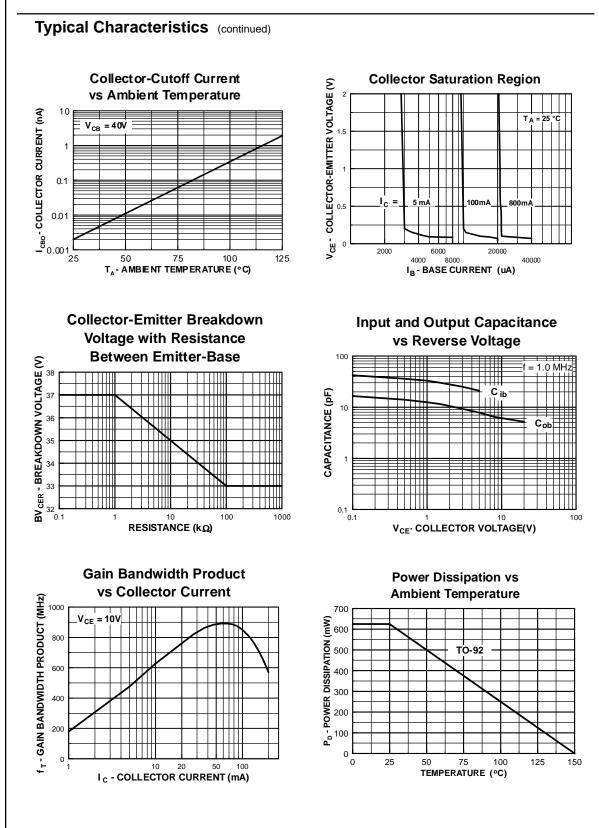
*Pulse Test: Pulse Width \leq 300 µs, Duty Cycle \leq 1.0%

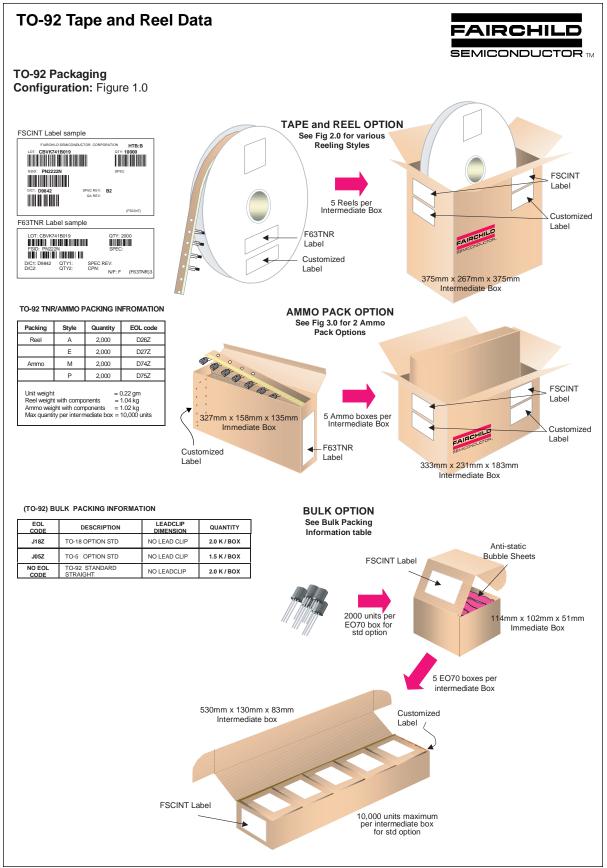
Typical Characteristics



MPS8050

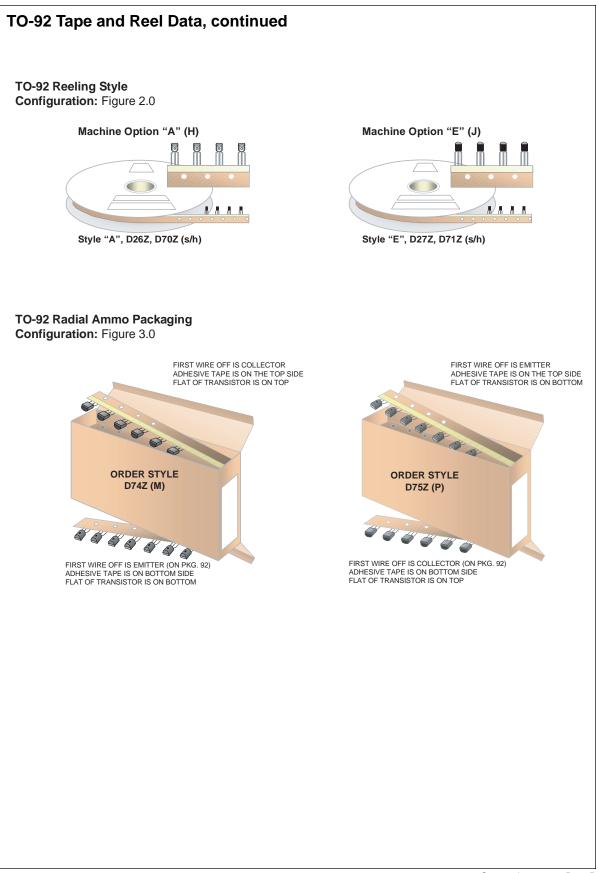


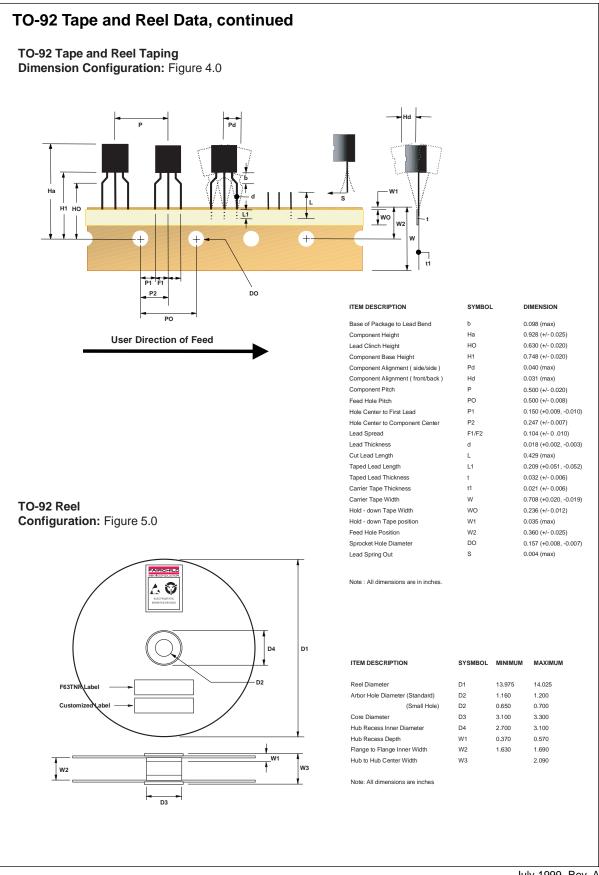




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